

# **SMA Ongoing Wideband Upgrade**

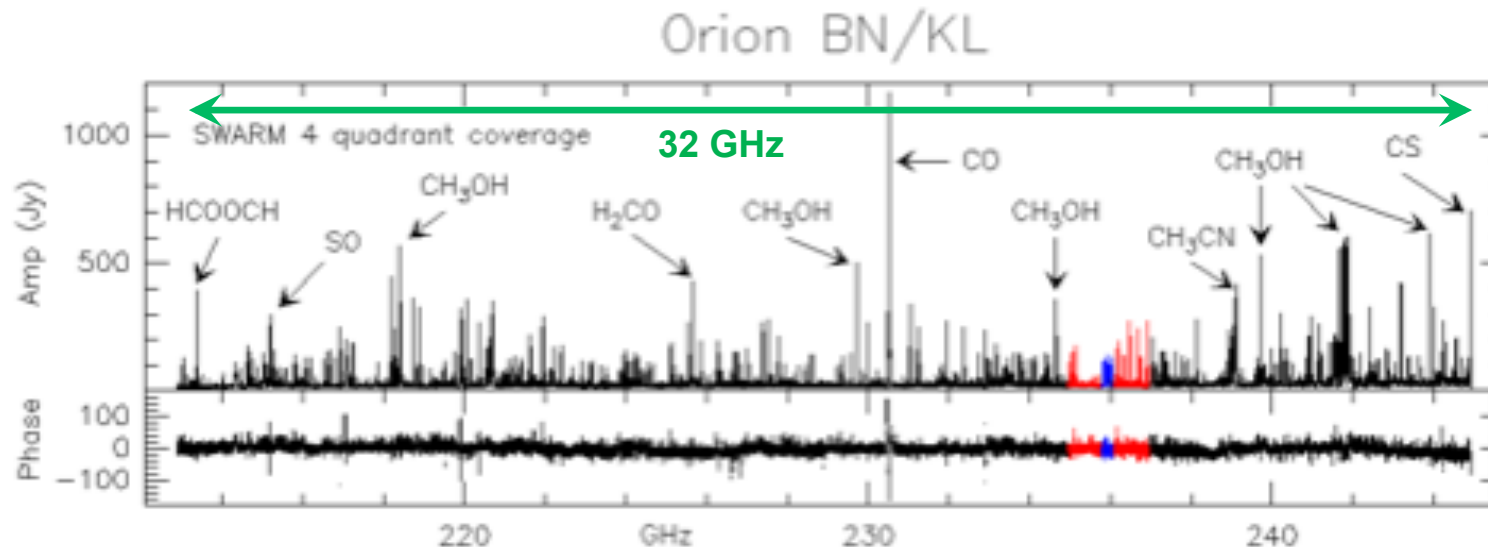
## **Upgrades leading to wSMA**

# How to further improve SMA sensitivity and throughput?

- Add more antennas?
- Increase the size of antennas?
- **Increase the instantaneous bandwidth of SMA**
  - > **Improve continuum sensitivity of SMA  $\Delta T \sim 1/\sqrt{B}$**
  - > **Catch more spectral lines with a single tuning**
- **Improve receiver noise temperature**
  - > **Remove room temperature optics**
- Going to multi-pixel

## Frontier for Radio Astronomy: Quest for Wider Bandwidth

- SMA is performing nightly observation with 32 GHz wide on-sky bandwidth thanks to wideband SIS receivers and SWARM.
- SWARM = Q1, Q2, Q3 + Q4, each quadrant handles 2 GHz DSB x 2 Rx
- 4 fold increase in BW compared to 10 years ago. Equivalent to collecting and processing 4 times as many photons.
- Can we go further in increasing the bandwidth? **YES**



32 GHz wide spectrum produced by the SWARM correlator of the Submillimeter Array (SMA), using 2x8 GHz Double-side-band IF of the SMA receivers. SWARM is powered by state-of-the-art fast digital FPGA processors.

# Upgrade Path of SMA

2018

**Current Status of SMA**  
**Dual DSB Rx**  
**4 - 12 GHz IF**  
**4Q SWARM**  
**32 GHz On sky BW**

2019

**Interim Upgrade**  
**Keep Cryostat**  
**4 - 16 GHz IF**  
**6Q SWARM**  
**48 GHz On sky BW**

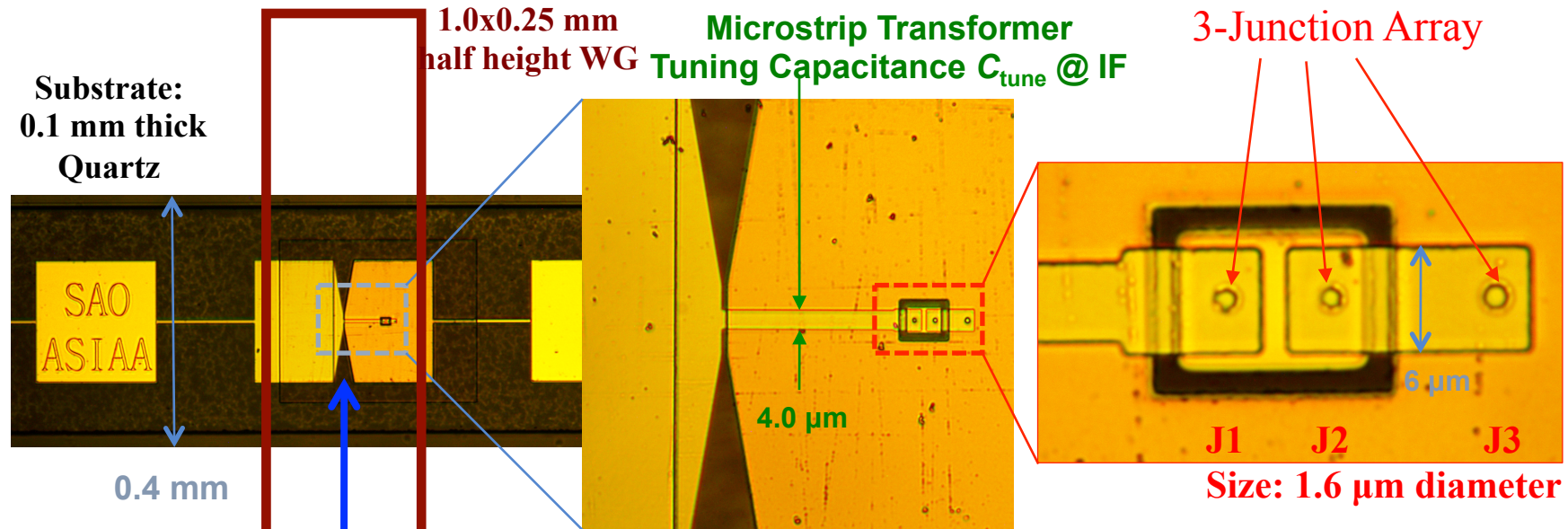
2021-  
2022

**wSMA Goal**  
**New Cryostat**  
**4 - 20 GHz IF (min)**  
**Next gen Correlator (?)**  
**> 64 GHz On sky BW**

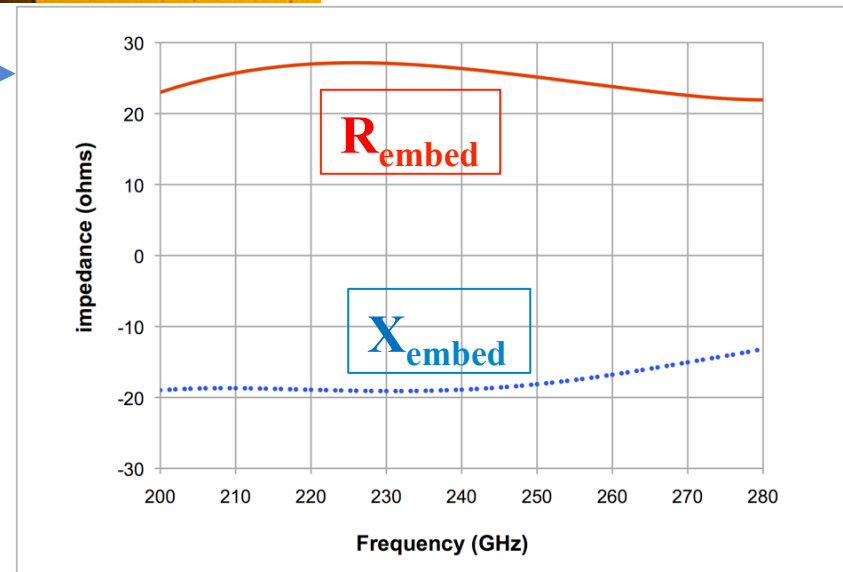
# Factors Limiting IF Bandwidth of SIS Mixers

- **High IF quantum effect (from Tucker Theory) phases in for  $IF > F_{LO}/10$ .**
- **Junction Capacitance --- Use small devices or **series junction array**.**
- **Output Saturation: Wider IF band leads to higher IF voltage swing across the junction. Max voltage swing is set by the width of photon step (LO frequency + # of junctions) -- -Reduce IF load impedance (Tan 2014) or use **series junction array**.**
- **SIS output match to Low Noise Amplifier (LNA)**
  1. **Direct interface (Rice 2002).**
  2. **Employ Impedance transformer (Tan 2014) .**
  3. **SIS device with High Current Density (Kojima 2017).**
  4. **Employ a wideband isolator in front of LNA.**
- **RF/IF Grounding of SIS Mixer -- Need to ground as close to device as possible.**

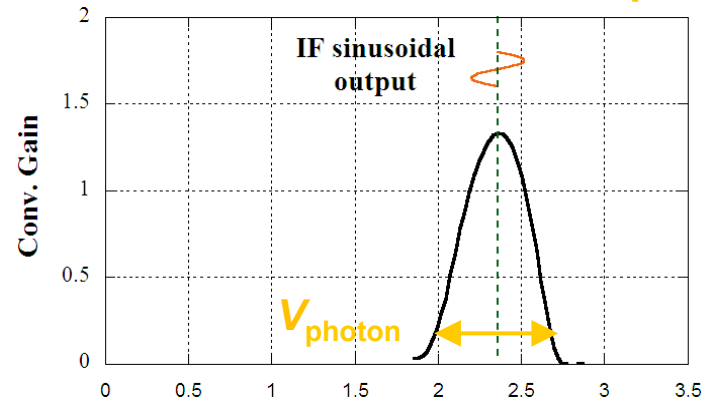
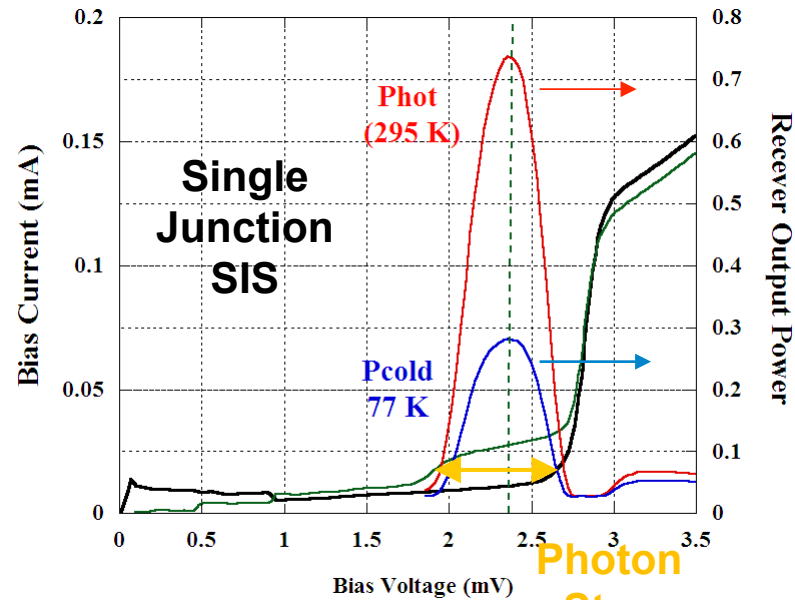
# SIS Mixer for wSMA-240



- $C_{array} = C_j / 3$
- $C_{mixer} = C_{array} + C_{tune} \sim 115$  fF.
- RC time constant of mixer gives  $F_{3dB} > 25$  GHz.



# Output Saturation in SIS Mixers



Power output of SIS mixer:

$$P_{\text{out}} = G_{\text{conv}} \times k_B T_{\text{inp}} B$$

$G_{\text{conv}} \sim 1$  : Conversion gain of SIS

$T_{\text{inp}} \sim 300$  K : Input (Antenna) Temp.

$B \sim 20$  GHz : Effective IF Bandwidth

$P_{\text{out}} \sim 10^{-10}$  W (100 pW)

RMS IF Voltage swing  $V_{\text{IF}}$ :

$$P_{\text{out}} = (V_{\text{IF}})^2 / R_L$$

$R_L \sim 50$   $\Omega$ : Load resistance

$V_{\text{IF}} \sim 7 \times 10^{-5}$  V (0.07 mV)

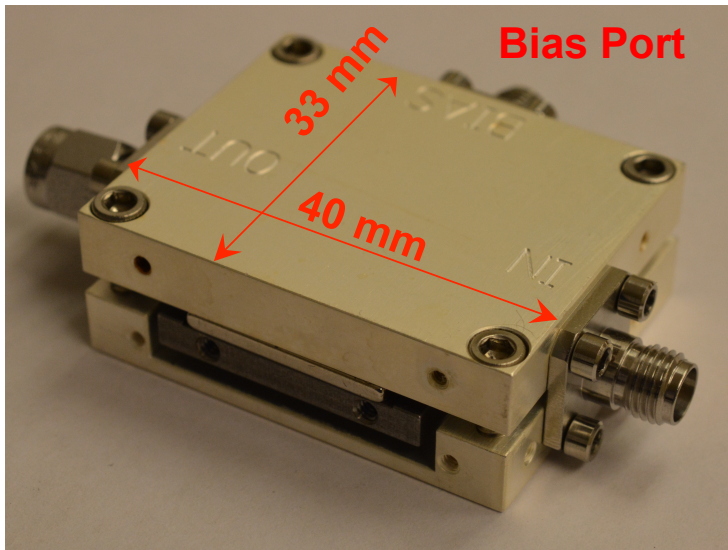
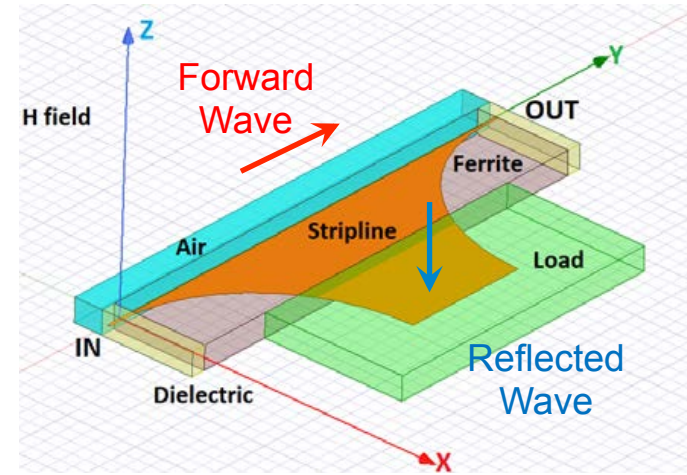
$$V_{\text{photon}} = N \times (hf_{\text{LO}} / e)$$

$$= N f_{\text{LO}} [\text{GHz}] / 242 \text{ mV}$$

Use of 3-junction array increases the power handling capacity of the SIS mixer by a factor of 3.

# Wideband Cryogenic Isolator Development at CfA

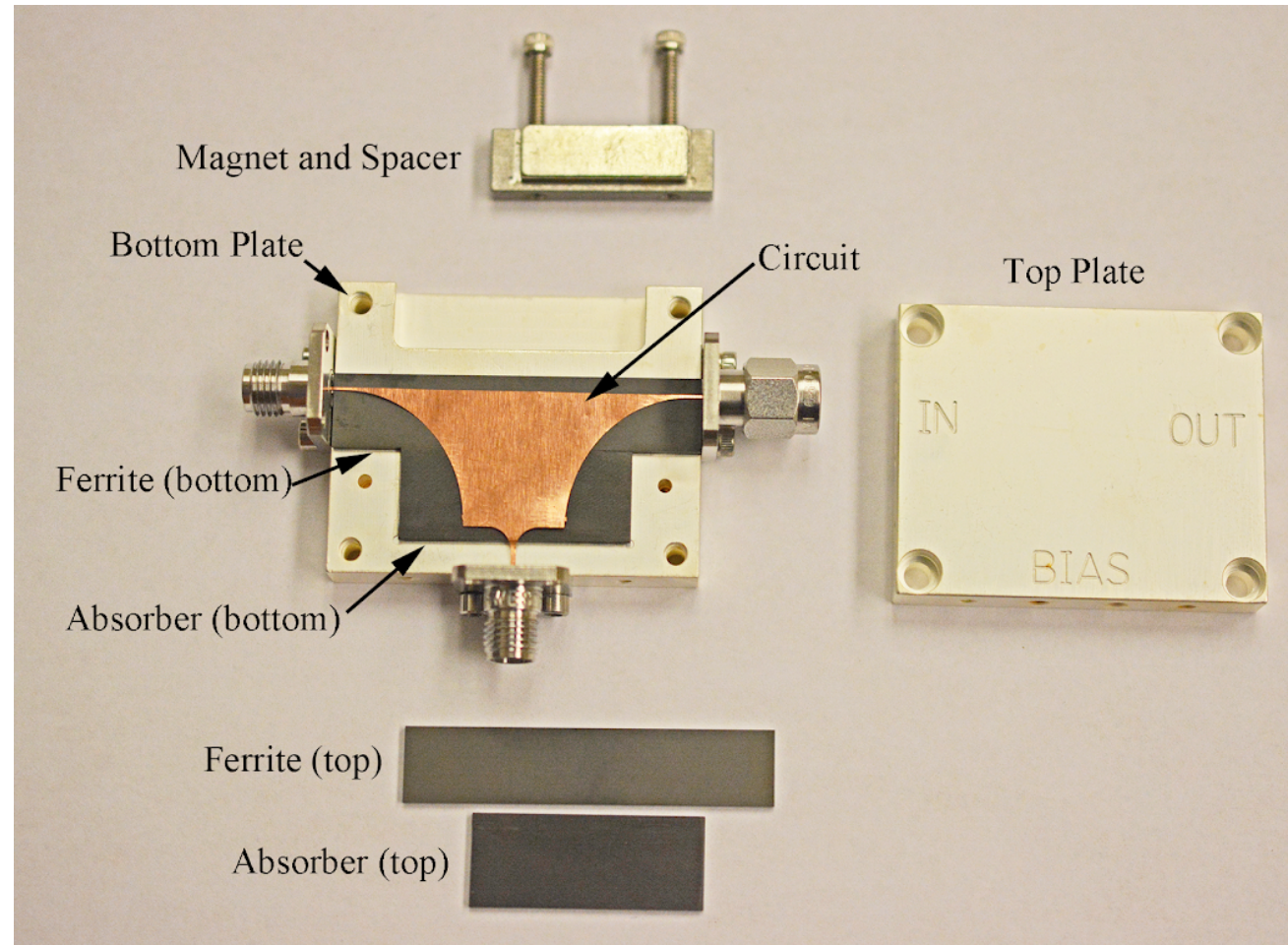
- Commercial cryogenic edge-mode isolator offers 3:1 BW operation.
- Quinstar 4-12 GHz isolator in use in many ALMA band.
- SMA uses a 4-14 GHz version from Quinstar
- We have developed a even wider band isolator



- Under DC magnetic field, RF current on ferrite stripline is displaced laterally, and becomes concentrated along the edge -- Edge-mode.
- By adding appropriate absorbing material, the reflected wave can be removed.



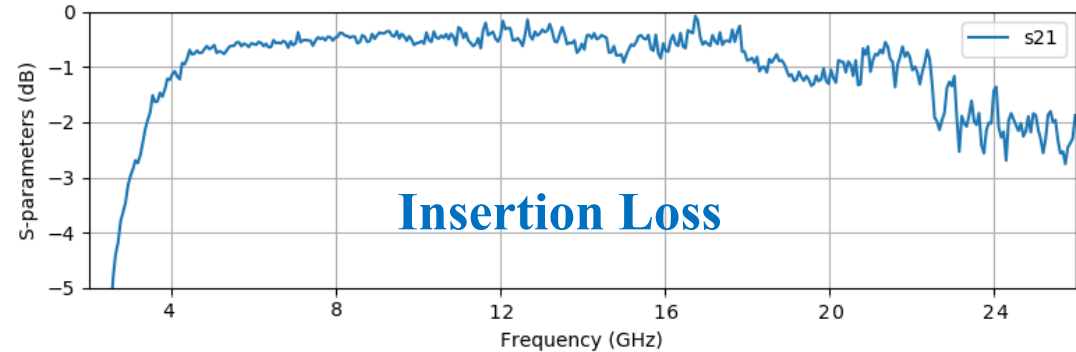
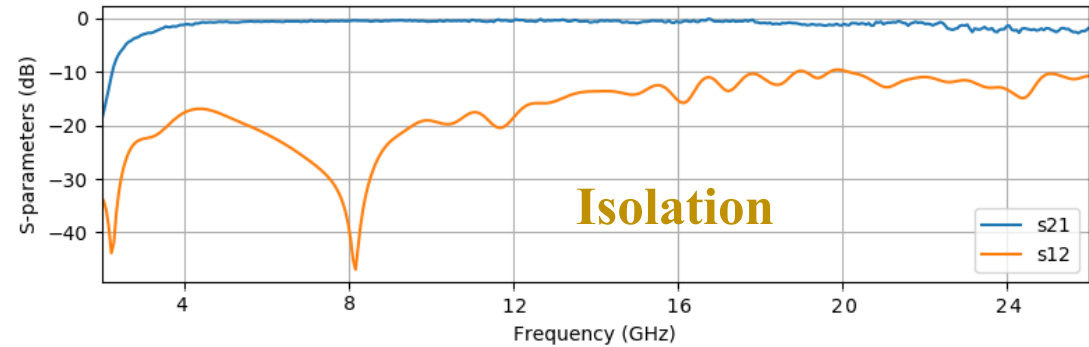
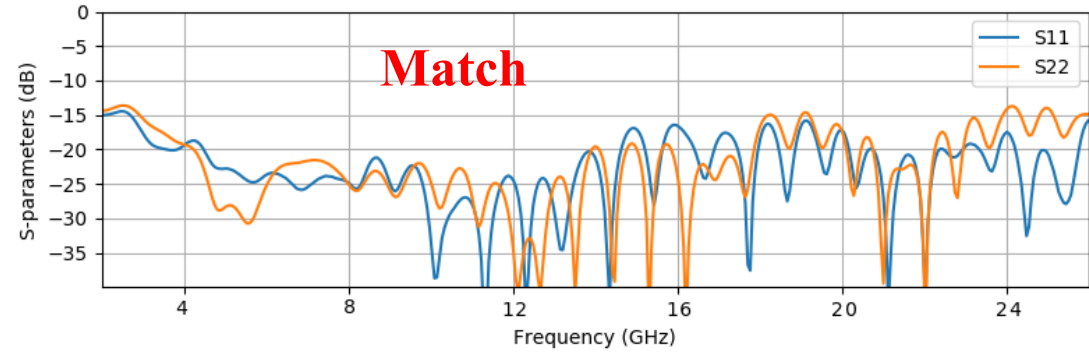
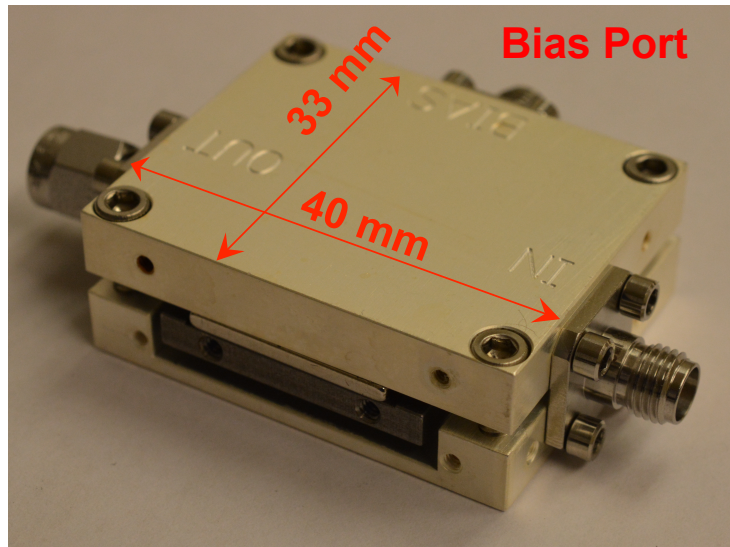
## Assembly Photo of SMA Wideband Isolator



*L. Zeng et al, "A low-loss edge-mode isolator with improved bandwidth for Cryogenic operation," IEEE Trans. Microwave Theory & Techniques, 2018. DOI: 10.1109/TMTT.2018.2799574*

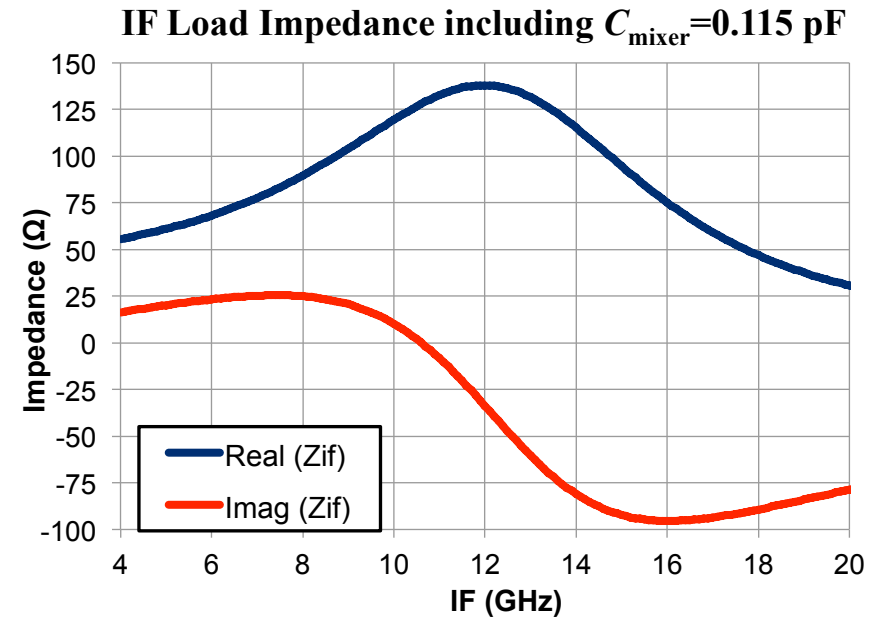
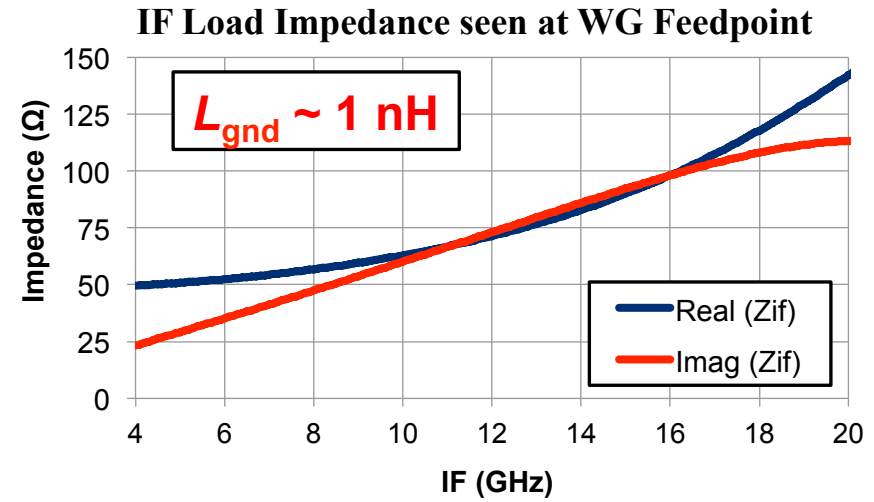
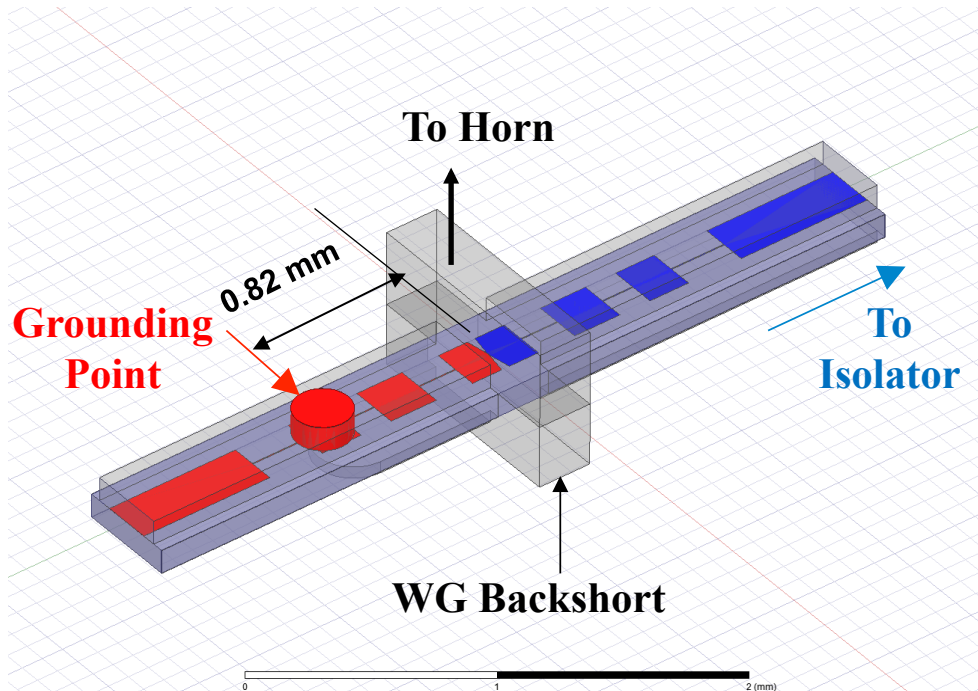
# Performance of Wideband Isolator at 4 K

- Insertion Loss  $< -1$  dB for 4 - 17 GHz, rising to 1 - 1.5 dB for 17 - 22 GHz
- Isolation  $< -15$  dB for 4 - 13 GHz, rising to 10 - 13 dB above 13 GHz
- Input & Output Match  $< -15$  dB

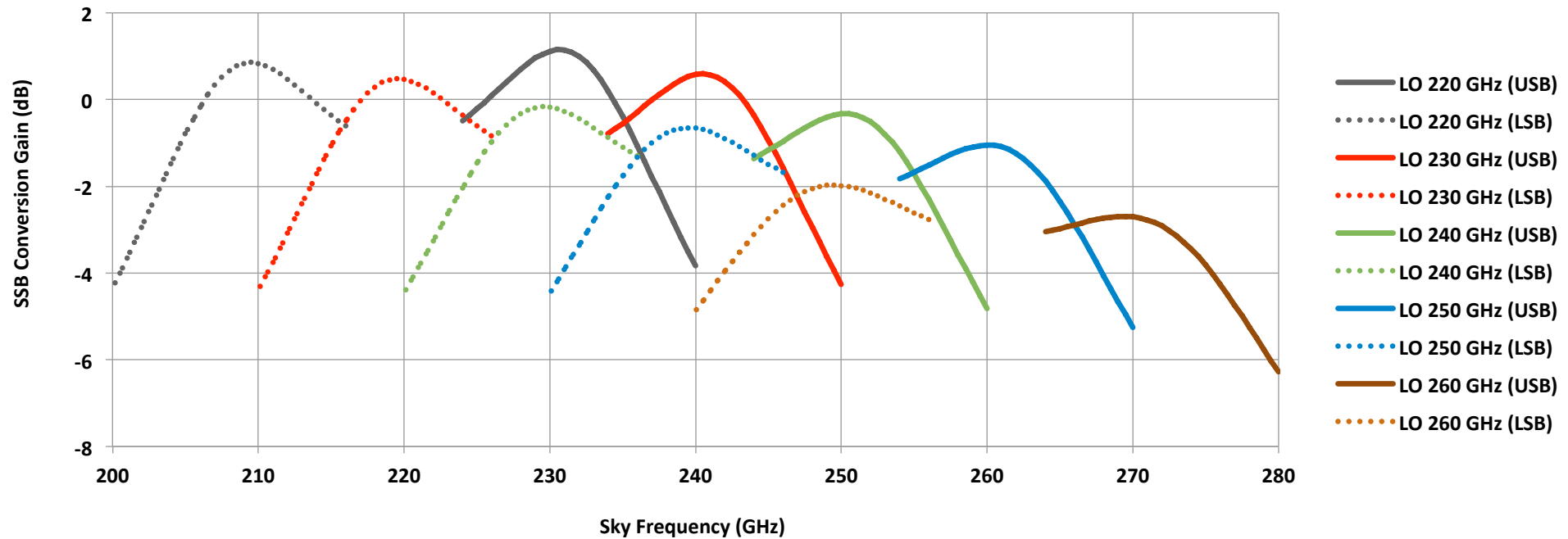


# Grounding of Mixer Chip

- Grounding of mixer chip may introduce extra inductance ( $L_{gnd}$ ) to the IF circuit.
- The extra load reactance may offset  $C_{mixer}$ , sum of junction & tuning circuit capacitances.
- Peak IF response of mixer occurs at resonance between  $L_{gnd}$  and  $C_{mixer}$



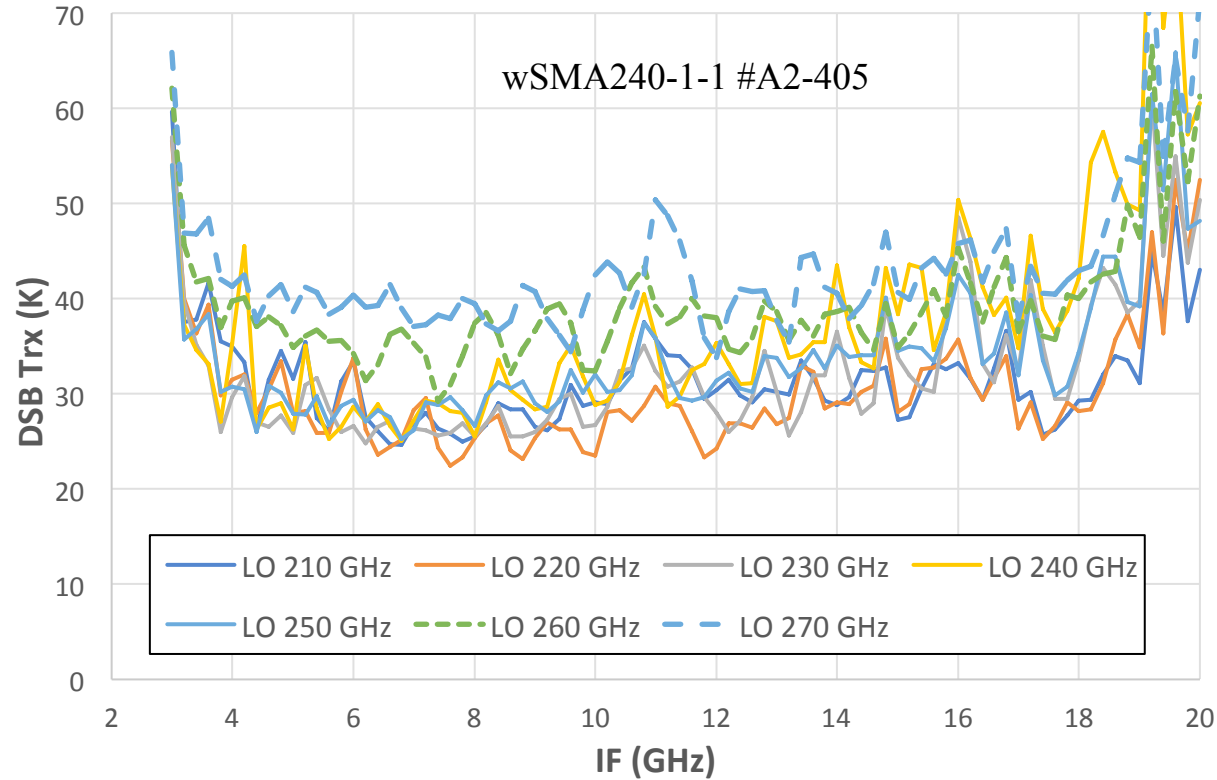
## Simulated Conversion Gain of wSMA-240 Mixer



- Peak IF response predicted at ~12 GHz
- Sideband ratio is within 1 dB, except at high LO
- DSB Conversion Gain is sum of USB & LSB Gain
- $G_{SSB} = 0$  dB translates into  $G_{DSB} = +3$  dB

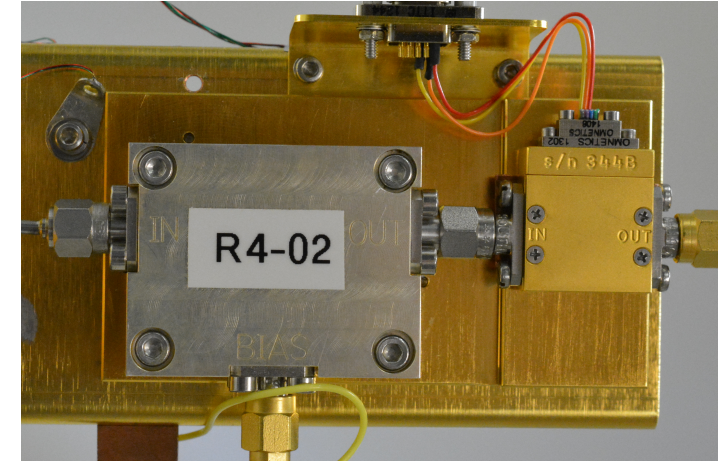
# Laboratory Results

Measured DSB Noise Temperature as a Function of IF

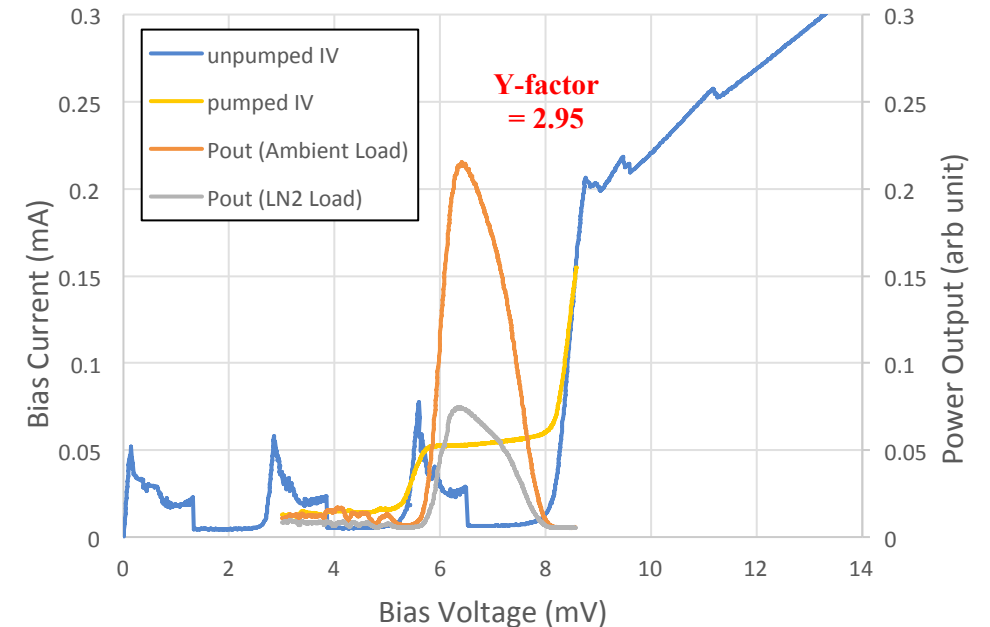


- Ripples in Trx Vs IF is linked to the 15 cm long coaxial cable between isolator and SIS mixer.

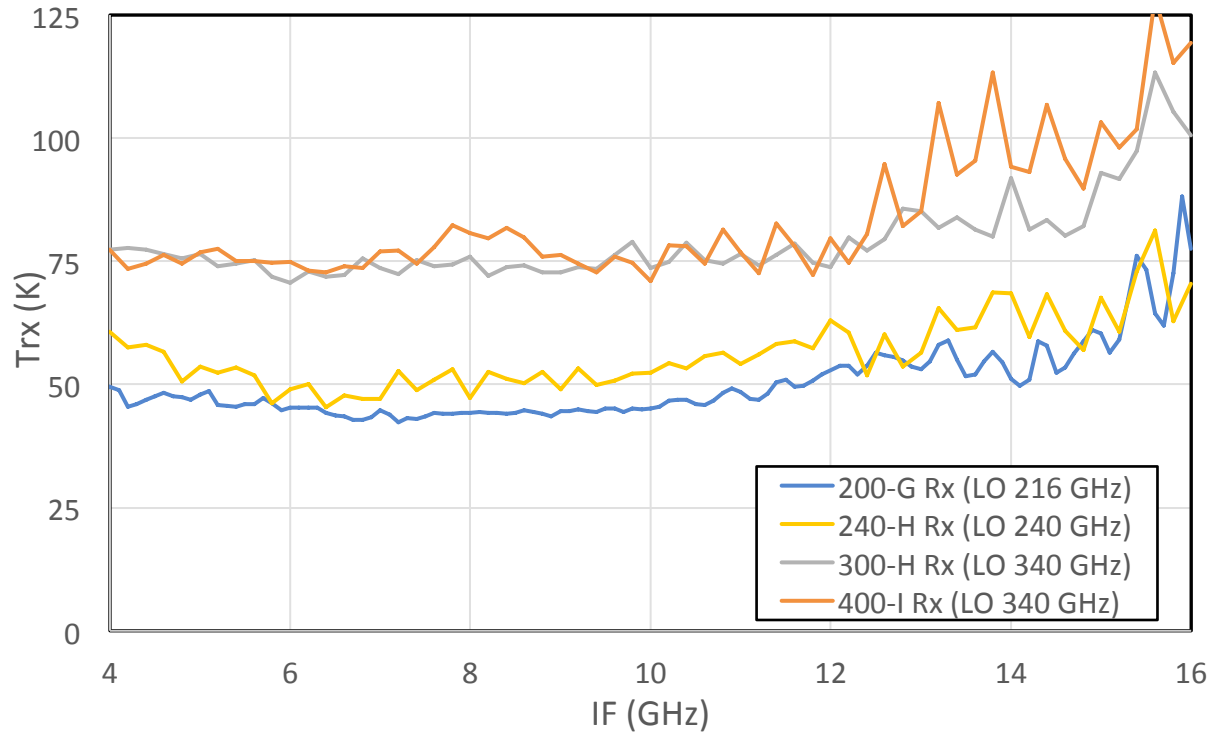
## SMA Cryo + LNF 6 - 20 GHz LNA



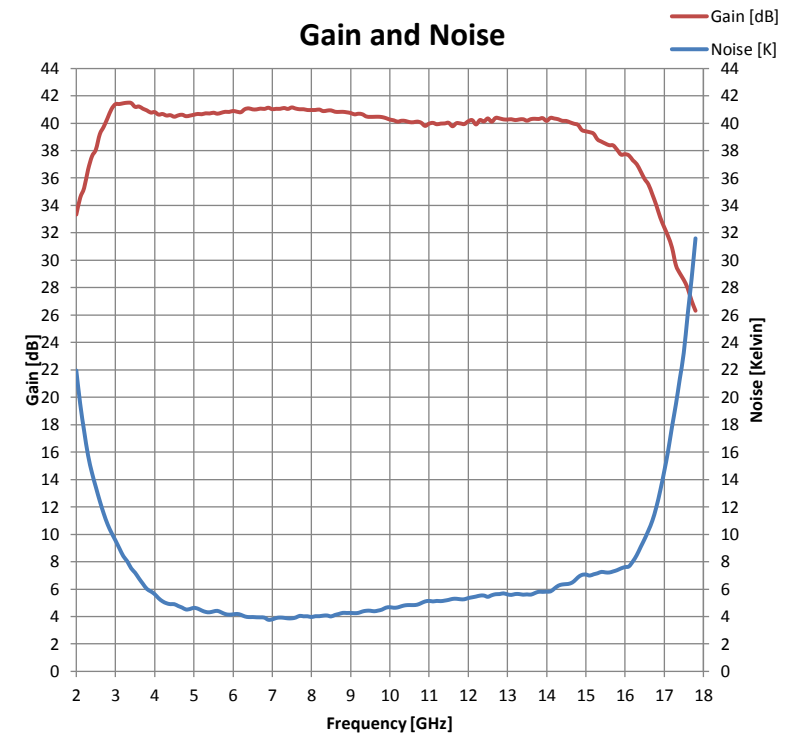
wSMA240-1-1 mixer: LO 230 GHz IF 18 GHz



# Performance of Receiver Inserts in Field

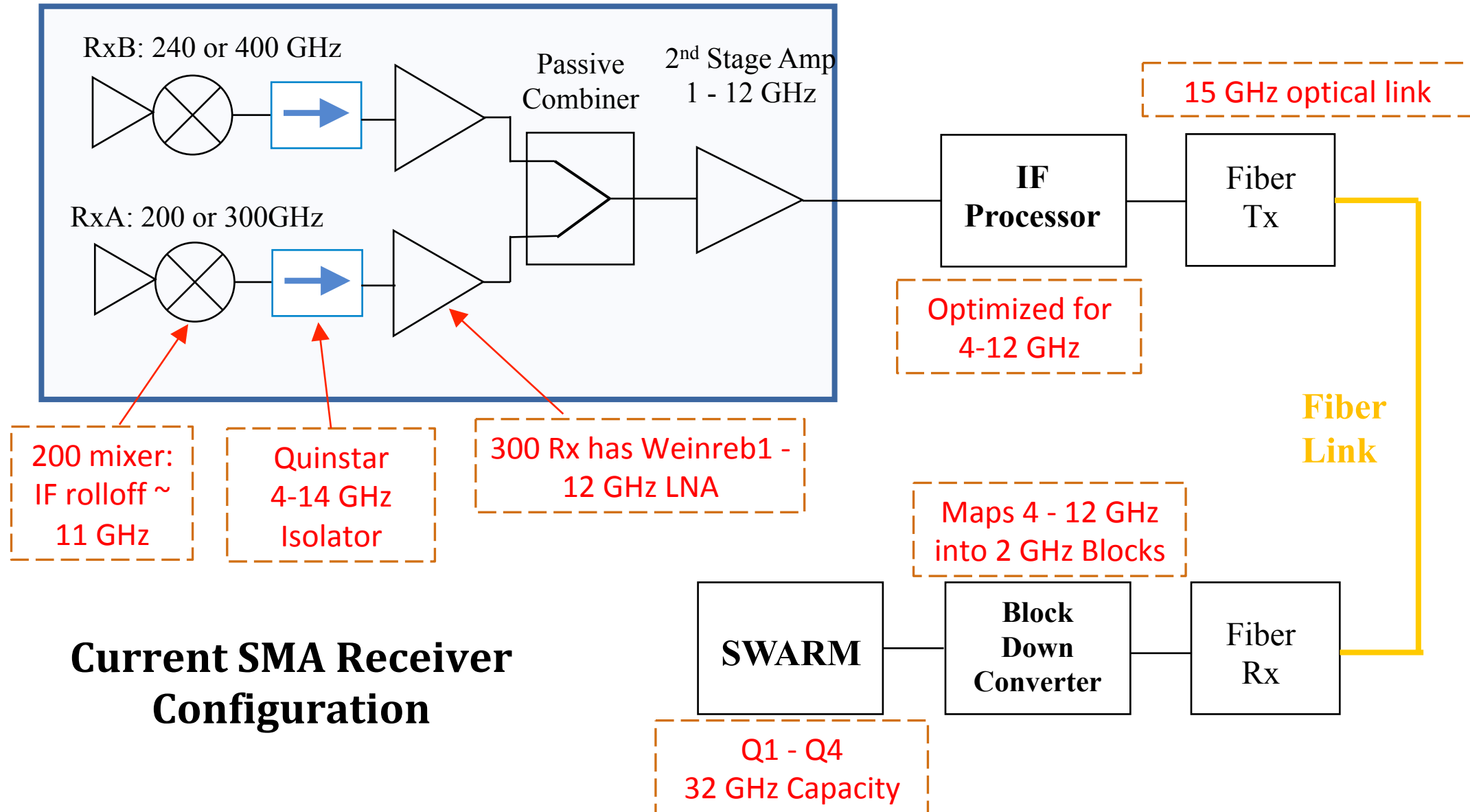


- **Quinstar 4 - 14 GHz Isolator**
- **LNF 4 - 16 GHz amplifier**



- **Trx data taken in lab but with full SMA optics**
- **Receiver noise @ 16 GHz IF is typically 40% higher than at 10 GHz.**
- **More noise ripples seen above 12 GHz IF due to poorer match.**

## SMA Cryostat showing one Rx Pair



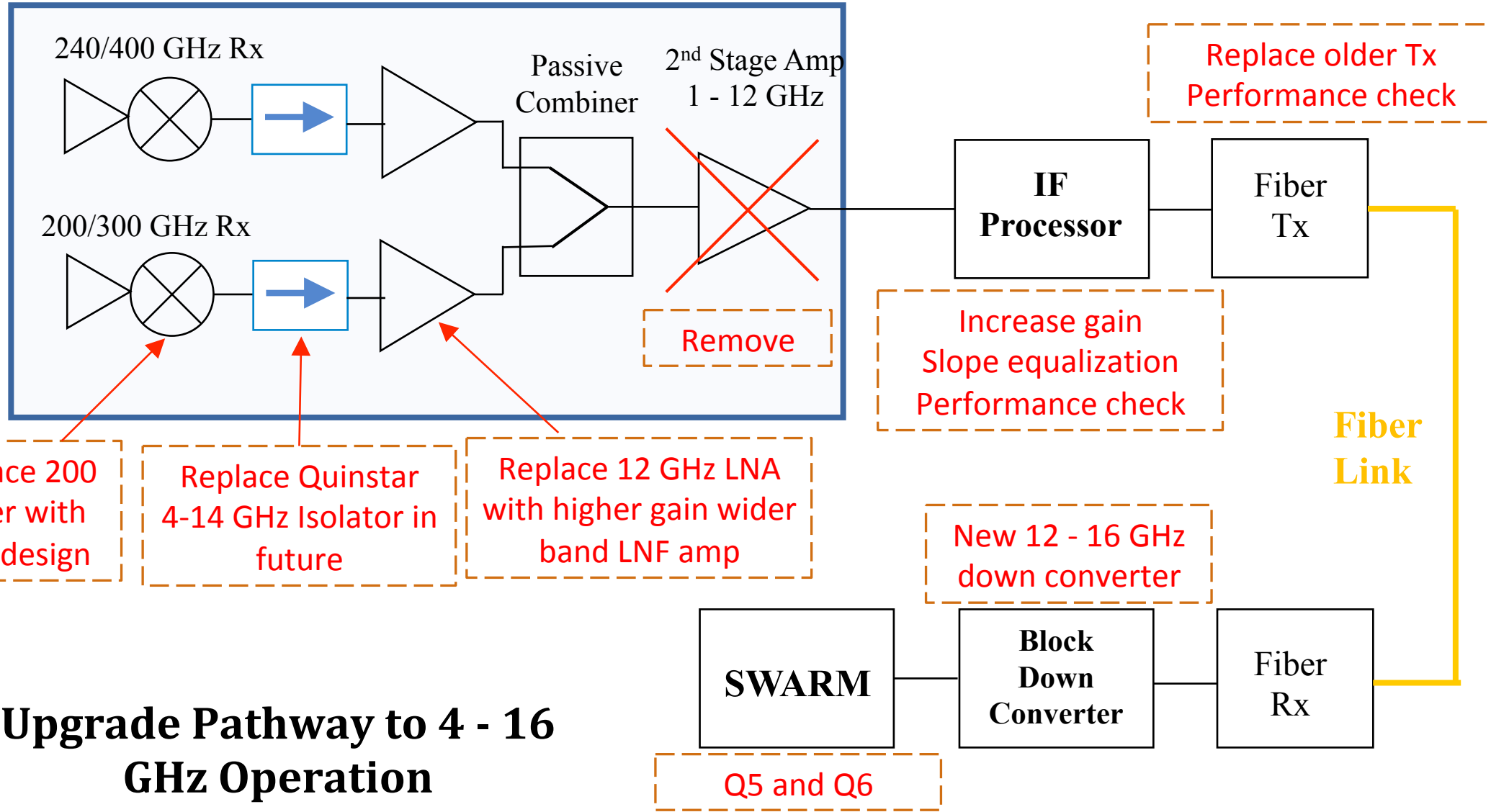
## Implementation of wider IF design into SMA operations

- **Replace existing SMA-200 mixers with new wSMA mixer chips.**
- **Use wider band LNA from LNF as first stage IF amplifier:**
  - LNC4\_16B covers 4 - 16 GHz (used already in many SMA Rx)**
  - LNC6\_20C covers <6 - 20 GHz (target LNA for future wSMA cryostat)**
- **Remove 2<sup>nd</sup> stage 12 GHz amplifier from inside cryostat.**
- **Introduce slope equalization in IF system.**
- **Replace old fiber transmitters.**
- **Add 12 - 16 GHz Block down-converter.**
- **Add SWARM Q5 and Q6 (Q5: 12-14 GHz; Q6: 14-16 GHz)**

**SMA will be operational with 4 - 16 GHz IF**



# SMA Cryostat showing one Rx Pair



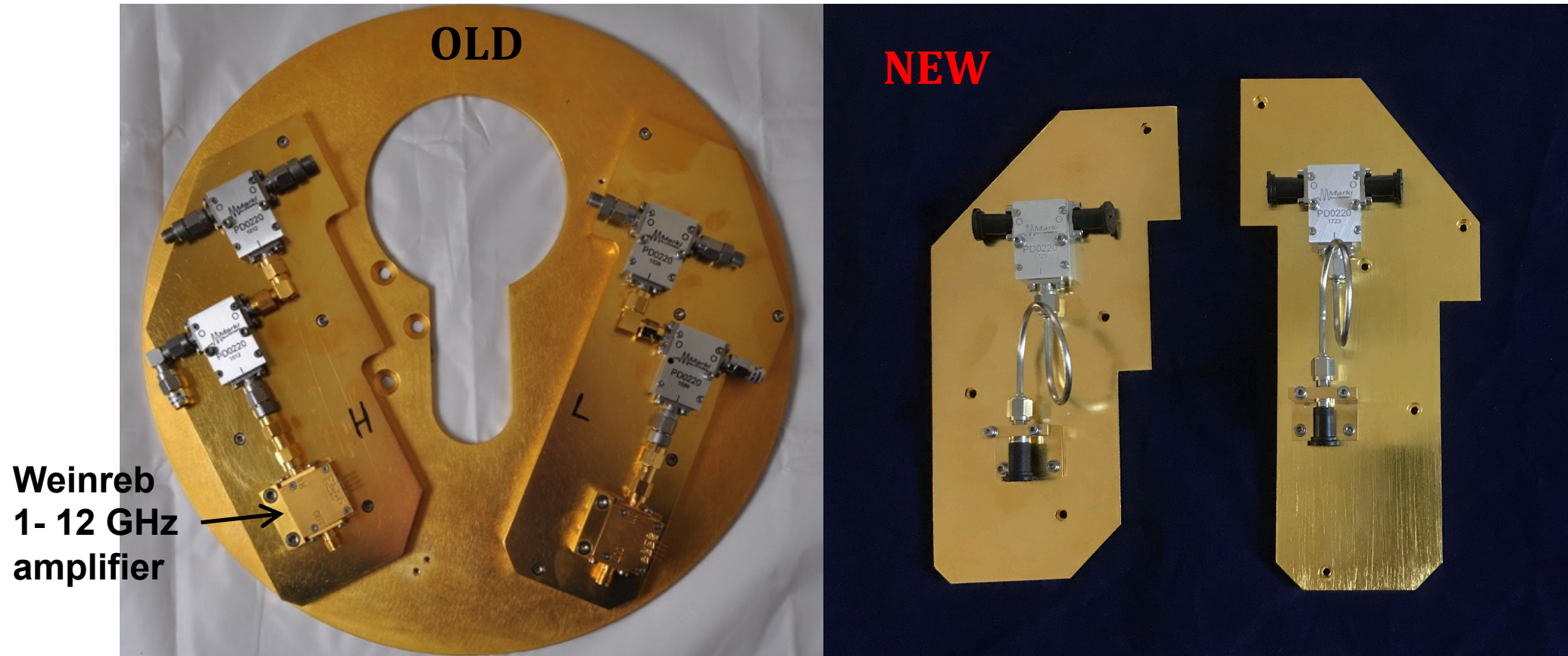
## Upgrade Pathway to 4 - 16 GHz Operation

## Removal of 2<sup>nd</sup> Stage Cryo amp (Limiting us to 12 GHz)

New LNA from LNF has higher gain (>35 dB). No need of 2<sup>nd</sup> stage cryogenic amp

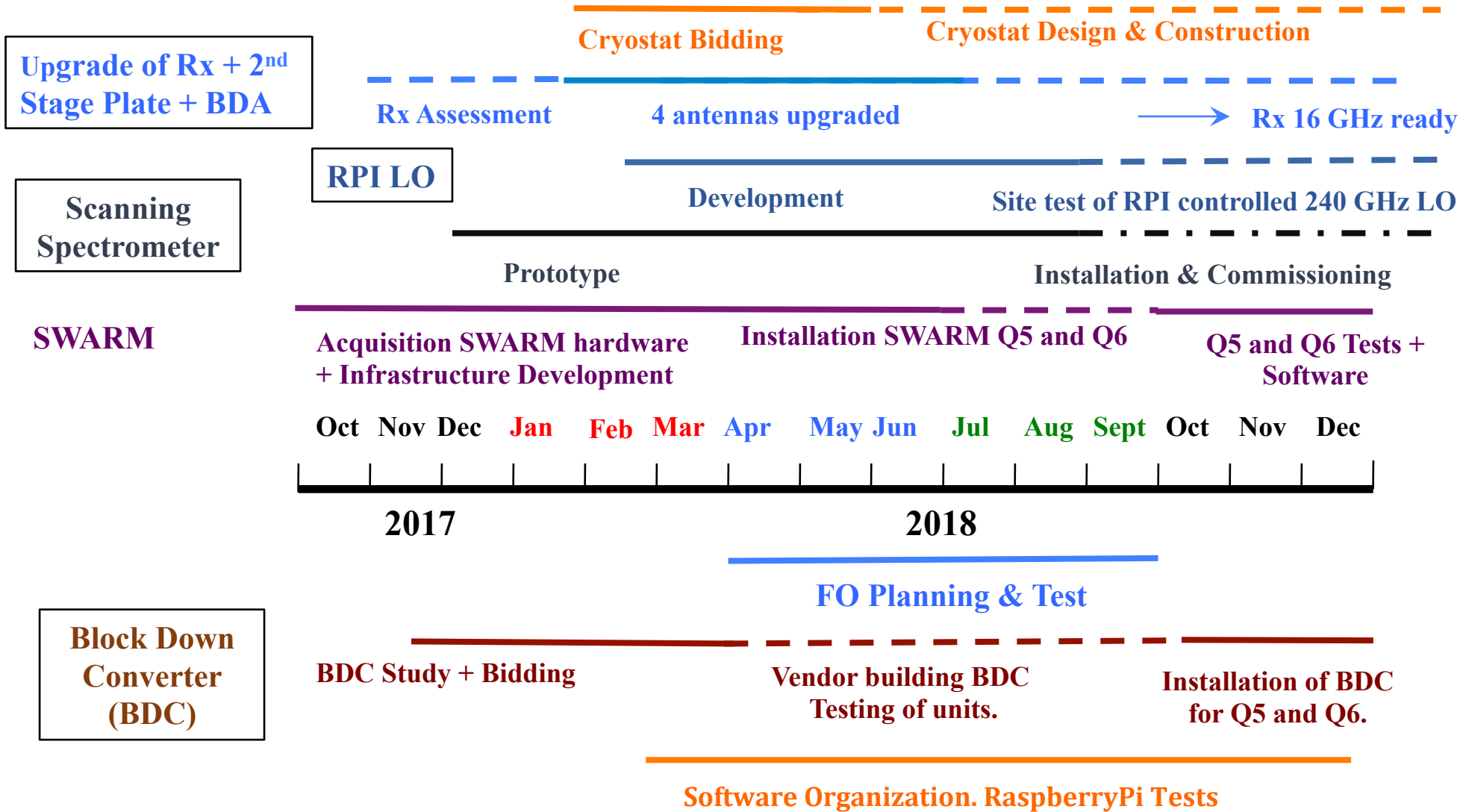
Two sets of New 2<sup>nd</sup> Stage plates have been prepared.

We plan to replace two cryostats each round. Outgoing plate and power splitters will be recycled.



## Status of wSMA 16 GHz Upgrade (June 2018)

Antenna	2 <sup>nd</sup> Stage Plate	200 Rx Upgrade	300 LNA Upgrade	IF Processor
1	X	X	X	X
2	X	X	ASIAA	X
3	X	X	ASIAA	X
4	Yes	Missing magnet	X	Yes
5	Yes	Yes	Yes	Yes
6	X	X	X	X
7	Yes	Yes	Yes	Yes
8	Yes	X	Yes	Yes

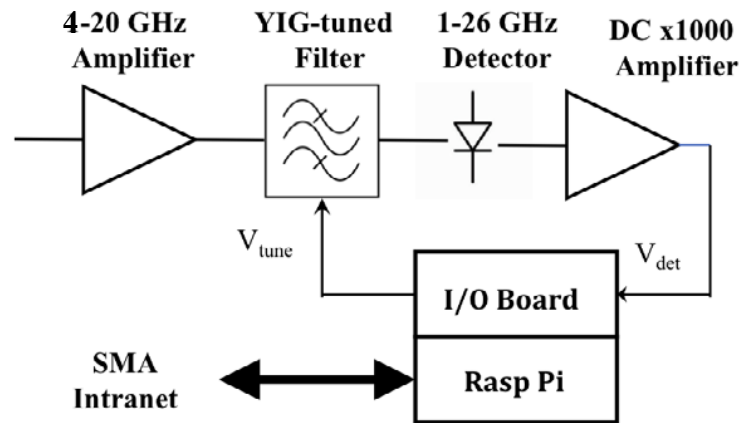


**wSMA Planning for 2018 as of 06/29/2018**

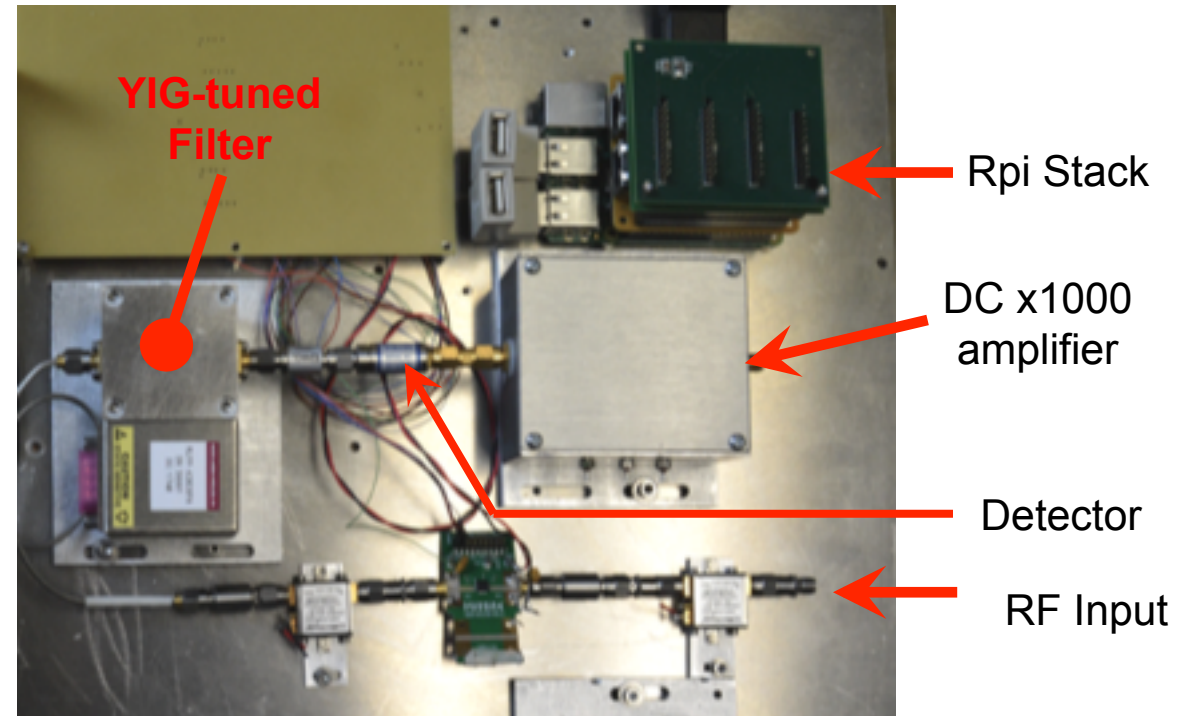
# **Technological Developments associated with wSMA**

- **Scanning Spectrometer**
- **Raspberry-Pi based Controllers**
- **Silicon based waveguide components**

# Scanning Spectrometer

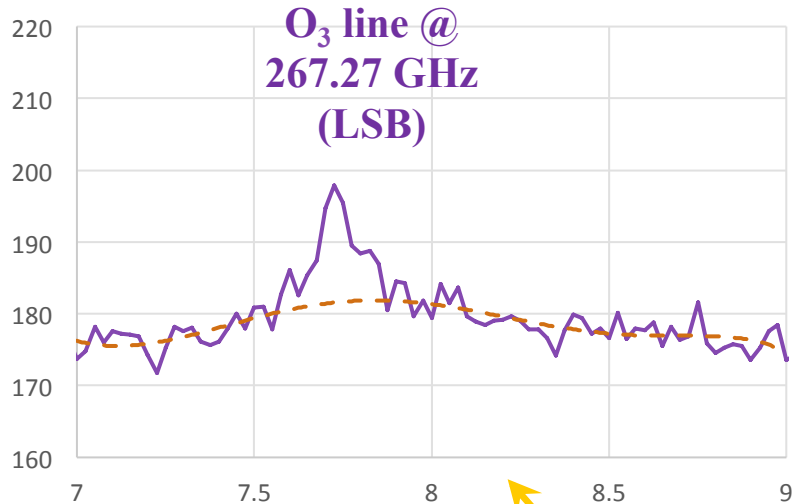


- To provide  $T_{sys}$  measurement as a function of IF (currently a single value of  $T_{sys}$  is logged)
- Useful for system diagnosis
- Able to observe atmospheric ozone lines.
- Resolution of YIG filter:  $\sim 30$  MHz
- Scan Time:  $\sim 0.5$  s

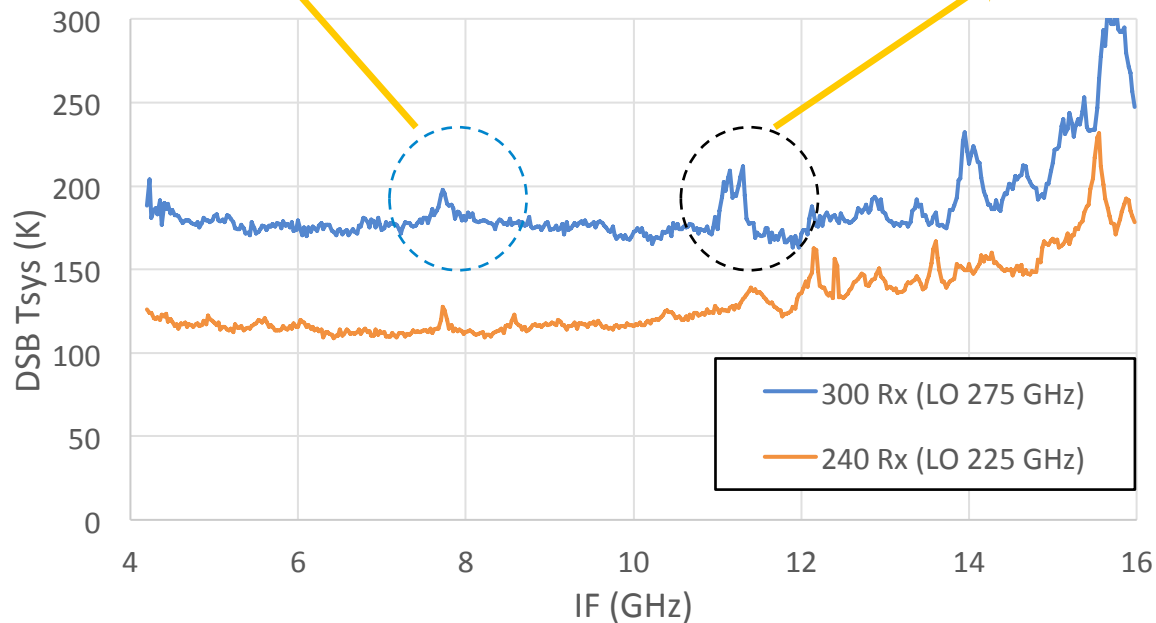
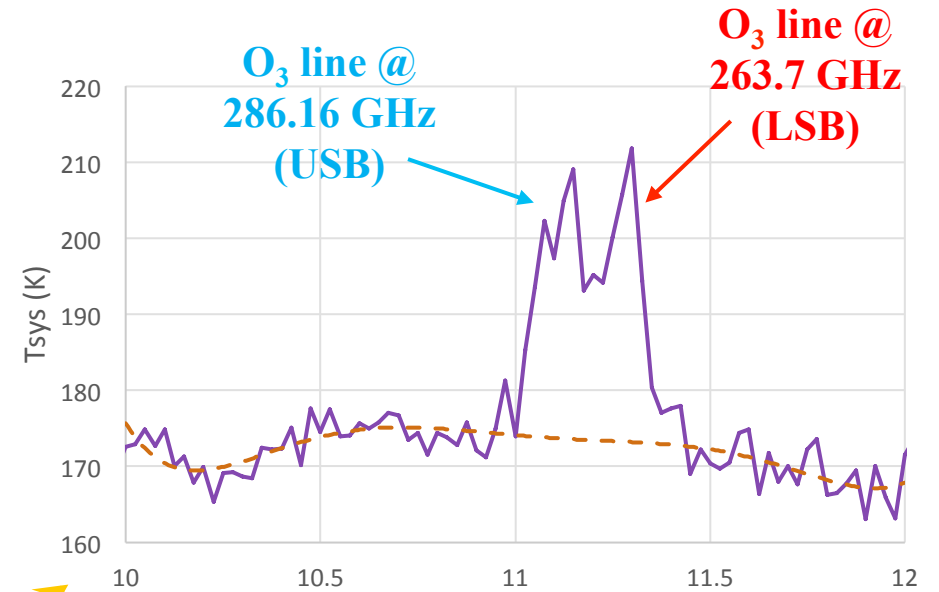


**RF amplifier chain  
+ Digital Attenuator**

- Prototype installed in antenna 7.
- Awaiting reorganization of network to synchronize with other real time components.
- Two more units to be installed in fall

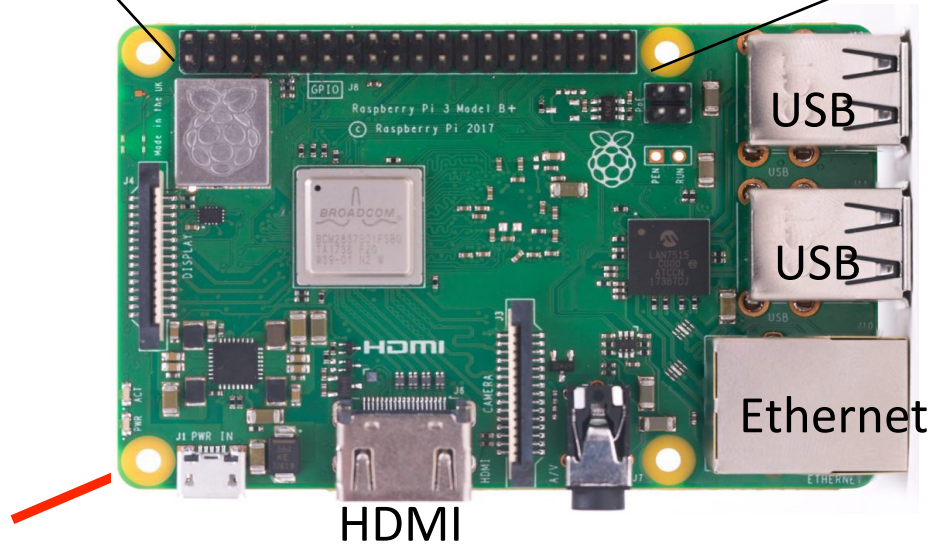
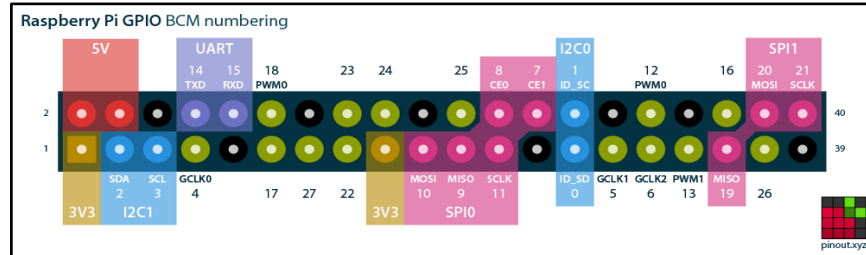


**2018-07-06  
Antenna 7  
Elevation 67°**



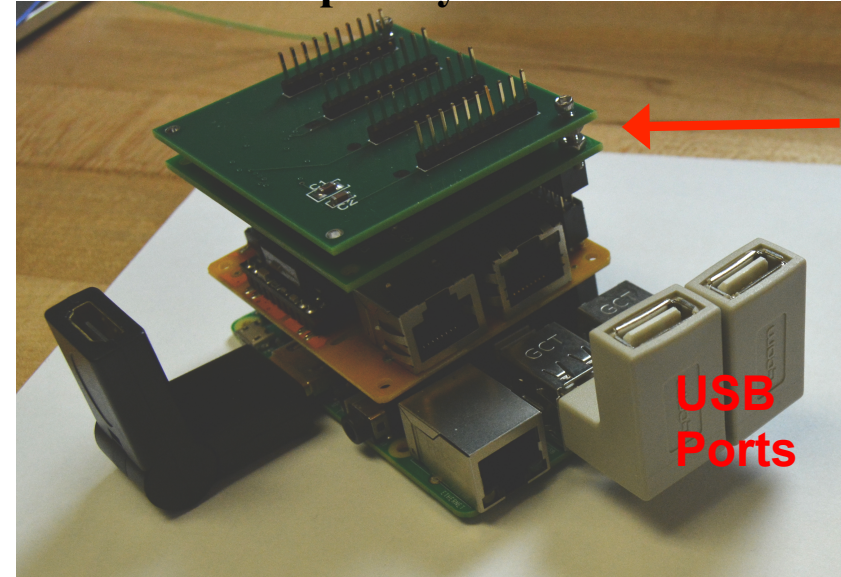
Tau225 ~ 0.150  
 Average of 8 scans  
 Integration time per channel  
 = 1.2 ms x 8 ~ 10 ms  
 Channel spacing 25 MHz  
 Expected baseline  $\Delta T \sim 0.3$  K  
 Observed  $\Delta T \sim 1 - 2$  K

# Raspberry Pi-based Controllers



Raspberry Pi model 3b+ showing various connectors plus the top 40-pin GPIO connectors

## Raspberry Pi Stack



Daughter & Grand-daughter Boards for IO

POE Board (Power on Ethernet)

- Low cost compact Linux computer allowing efficient analog & digital I/O interface thru add-on boards
- Very useful as distributed controllers, remotely accessible through its ethernet port.



# Testing RPi on Mauna Kea

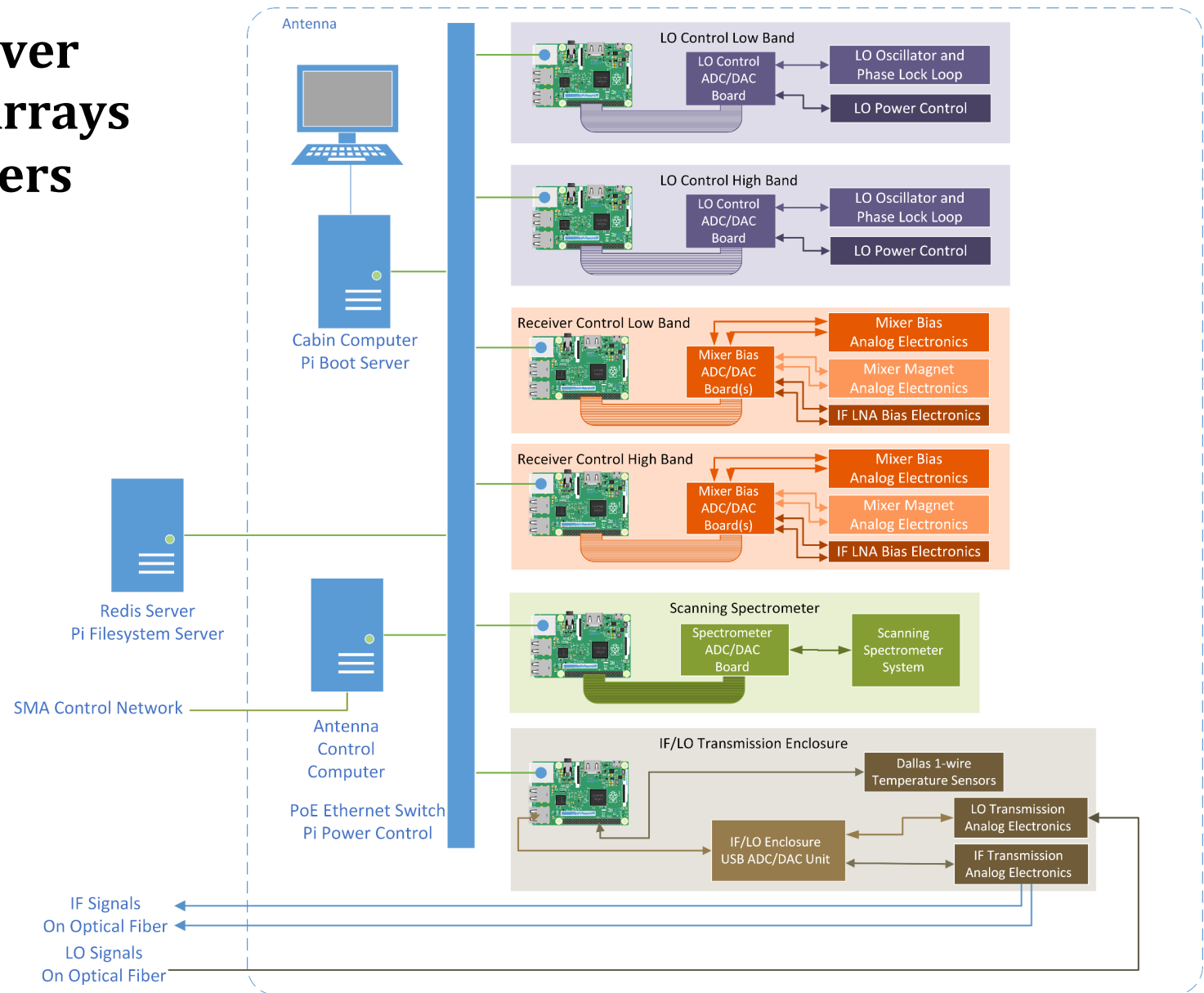
- We power the RPi with a PoE (Power on Ethernet) board.
- PoE removes the necessity of an external power supply & UPS for the RPi and it allows remote power cycling through the PoE switch.
- Remote booting simplifies management since we could have as many as 8 RPi in each cabin.
- We have run batches of RPi (Pi Patches) on Mauna Kea for more than a year, with a cumulative up time of ~4 Pi year without failure.



Latest Pi Patch to be tested on Mauna Kea with the final hardware configuration.

# Distributed wSMA Receiver Control system based on Arrays of RaspberryPI Controllers

- “RaspberryPIs in the wSMA” poster by Paul Grimes & Ram Rao
- Rao, Grimes, Leiker et al, “The Submillimeter Array needs some Raspberry Pis!!” in SMA Newsletter July 2018
- A RPi group led by Ram is laying down the ground work for future wSMA control system.

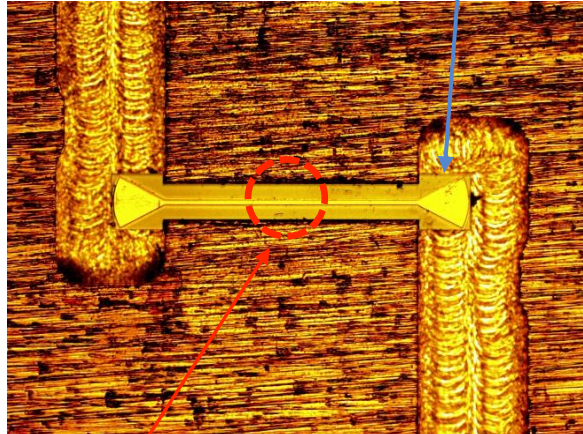


# Development of Silicon Technology for wSMA

- High resistivity silicon has low losses up to THz frequency range.
- Processing of silicon micro-structures is a mature technology.
- Silicon chips with  $\mu\text{m}$  thickness can be manipulated easily.
- Joint development with ASIAA, using their nanofabrication capability.

# Optically Controlled Waveguide Variable Attenuator

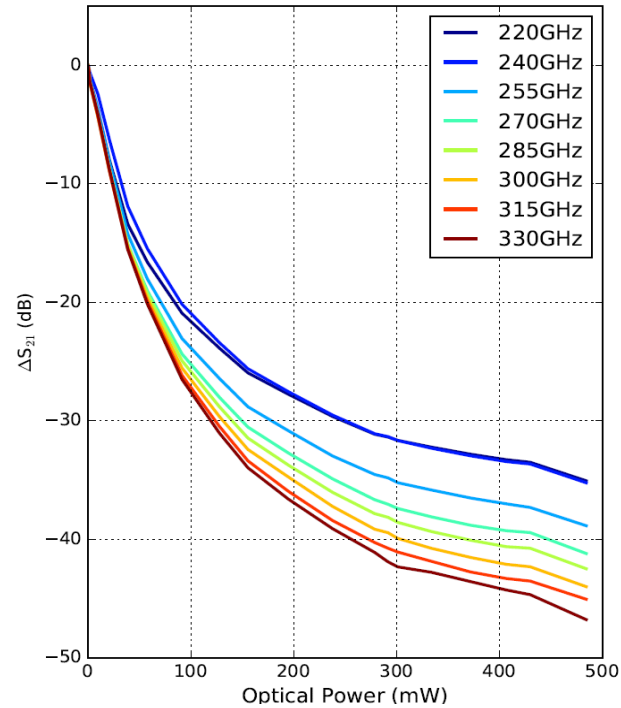
WR-3.4 Output



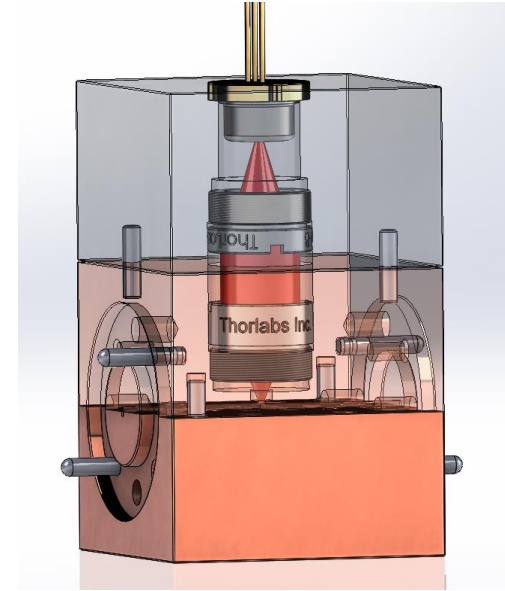
Silicon Chip  
25  $\mu\text{m}$  thick

Laser Light  
Illumination  
 $\lambda \sim 850 \text{ nm}$

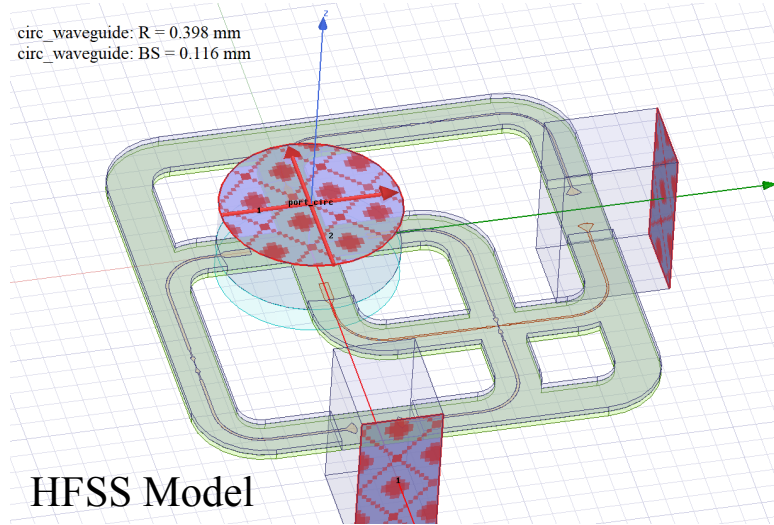
WR-3.4 Input  
220-340 GHz



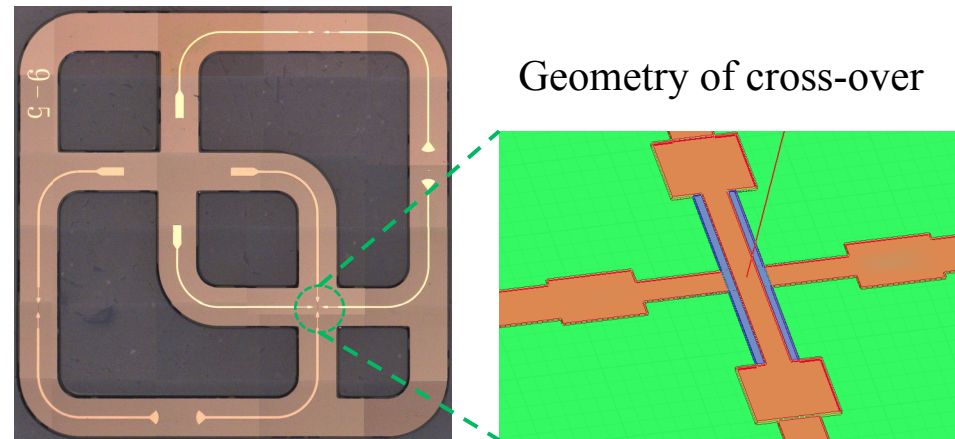
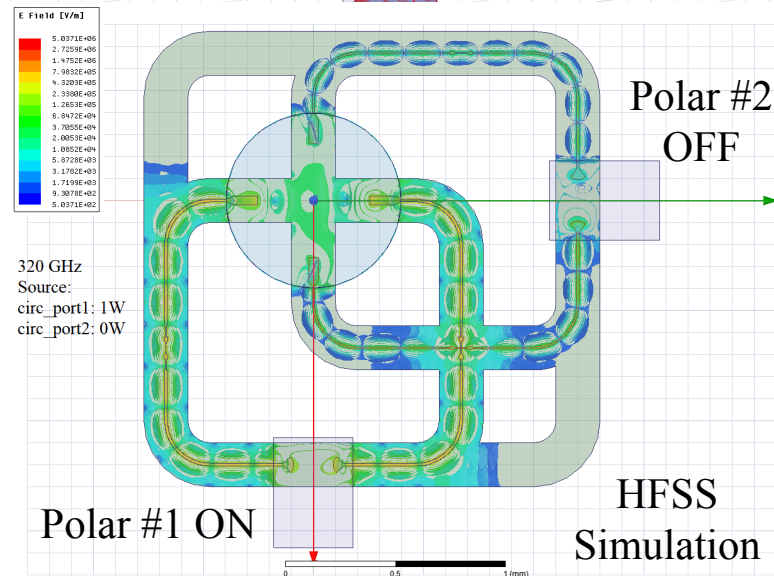
- Insertion Loss: 1 - 1.5 dB
- Response Time  $\sim 1 \text{ ms}$
- Laser DC power  $\sim 0.3 \text{ W}$  for 100 mW optical power
- Will be used as in wSMA LO power control.



# Orthomode Transducer (OMT) Based on Si Chip



- New wSMA Rx will use a waveguide OMT to separate the 2 polarizations
- Design tested in a 10 GHz scaled model
- 25  $\mu\text{m}$  thick Si chip for 280-360 GHz
- Design with HFSS
- Isolation between polarizations  $> 25$  dB
- Chips fabricated. Handle is easy
- Waiting for testing fixture.



# Silicon Based LO Coupler

- Level of coupling can be adjusted by changing chip
- Machining tolerances are more relaxed.

